

**2N60-LC1****Power MOSFET****2.0A, 600V N-CHANNEL  
POWER MOSFET****■ DESCRIPTION**

The UTC **2N60-LC1** is an N-channel power MOSFET using UTC's advanced technology to provide customers with a minimum on-state resistance and superior switching performance.

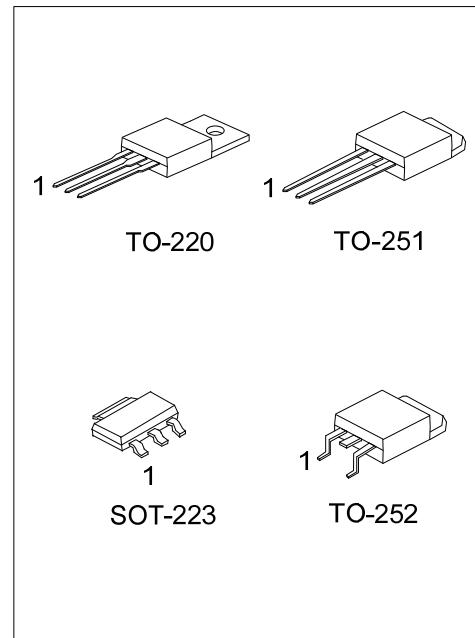
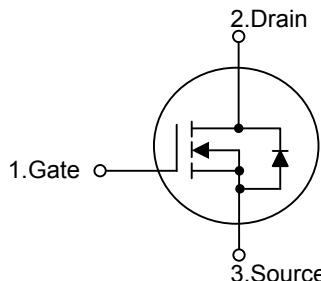
The UTC **2N60-LC1** is generally applied in low power switching mode power appliances and electronic ballast.

**■ FEATURES**

- \*  $R_{DS(ON)} \leq 5.0 \Omega$  @  $V_{GS}=10V$ ,  $I_D=1.0A$

- \* High Switching Speed

- \* 100% Avalanche Tested

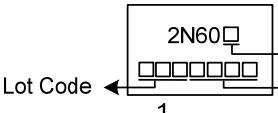
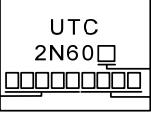
**■ SYMBOL****■ ORDERING INFORMATION**

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2N60L-AA3-R	2N60G-AA3-R	SOT-223	G	D	S	Tape Reel
2N60L-TA3-T	2N60G-TA3-T	TO-220	G	D	S	Tube
2N60L-TM3-T	2N60G-TM3-T	TO-251	G	D	S	Tube
2N60L-TN3-R	2N60G-TN3-R	TO-252	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

2N60G-TA3-T   	(1)R: Tape Reel, T: Tube (2)AA3: SOT-223, TA3: TO-220, TM3: TO-251, TN3: TO-252 (3)G: Halogen Free and Lead Free, L: Lead Free
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### ■ MARKING

SOT-223	TO-220 / TO-251 / TO-252
 <p>2N60□ Lot Code ← 1 Date Code</p> <p>L: Lead Free G: Halogen Free</p>	 <p>UTC 2N60□ Lot Code ← 1 Date Code</p> <p>L: Lead Free G: Halogen Free</p>

■ ABSOLUTE MAXIMUM RATINGS ( $T_c=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	600	V
Gate-Source Voltage		$V_{GSS}$	$\pm 30$	V
Drain Current	Continuous	$I_D$	2	A
	Pulsed (Note 2)	$I_{DM}$	4	A
Avalanche Energy	Single Pulsed (Note 3)	$E_{AS}$	33.8	mJ
Peak Diode Recovery $dv/dt$ (Note 4)		$dv/dt$	2.6	V/ns
Power Dissipation	SOT-223	$P_D$	2.3	W
	TO-220		54	W
	TO-251/TO-252		45	W
Junction Temperature		$T_J$	+150	$^\circ\text{C}$
Storage Temperature		$T_{STG}$	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3.  $L = 10\text{mH}$ ,  $I_{AS} = 2.6\text{A}$ ,  $V_{DD} = 50\text{V}$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^\circ\text{C}$

4.  $I_{SD} \leq 2.0\text{A}$ ,  $di/dt \leq 200\text{A}/\mu\text{s}$ ,  $V_{DD} \leq BV_{DSS}$ , Starting  $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SOT-223	$\theta_{JA}$	160	$^\circ\text{C/W}$
	TO-220		62.5	$^\circ\text{C/W}$
	TO-251/TO-252		100	$^\circ\text{C/W}$
Junction to Case	SOT-223	$\theta_{JC}$	54	$^\circ\text{C/W}$
	TO-220		2.32	$^\circ\text{C/W}$
	TO-251/TO-252		2.77 (Note)	$^\circ\text{C/W}$

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

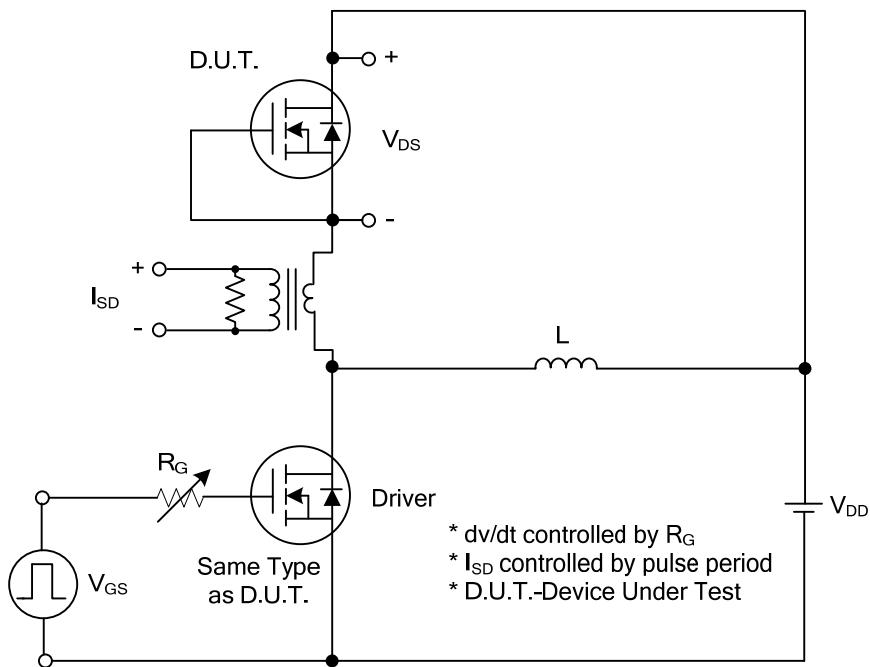
■ ELECTRICAL CHARACTERISTICS ( $T_J=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$I_D=250\mu\text{A}, V_{GS}=0\text{V}$	600			V
Drain-Source Leakage Current	$I_{\text{DSS}}$	$V_{DS}=600\text{V}, V_{GS}=0\text{V}$			10	$\mu\text{A}$
Gate- Source Leakage Current	Forward	$V_{GS}=+30\text{V}, V_{DS}=0\text{V}$			+100	nA
	Reverse	$V_{GS}=-30\text{V}, V_{DS}=0\text{V}$			-100	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{DS(\text{ON})}$	$V_{GS}=10\text{V}, I_D=1.0\text{A}$			5.0	$\Omega$
<b>DYNAMIC PARAMETERS</b>						
Input Capacitance	$C_{\text{ISS}}$	$V_{GS}=0\text{V}, V_{DS}=25\text{V}, f=1.0\text{MHz}$	285			pF
Output Capacitance	$C_{\text{OSS}}$		30			pF
Reverse Transfer Capacitance	$C_{\text{RSS}}$		2.3			pF
<b>SWITCHING PARAMETERS</b>						
Total Gate Charge (Note 1)	$Q_G$	$V_{DS}=480\text{V}, V_{GS}=10\text{V}, I_D=2\text{A}$ $I_G=1\text{mA}$ (Note 1, 2)	7			nC
Gate to Source Charge	$Q_{GS}$		2.9			nC
Gate to Drain Charge	$Q_{GD}$		0.9			nC
Turn-ON Delay Time (Note 1)	$t_{D(\text{ON})}$	$V_{DD}=100\text{V}, V_{GS}=10\text{V},$ $I_D=2\text{A}, R_G=25\Omega$ (Note 1, 2)	4			ns
Rise Time	$t_R$		14.5			ns
Turn-OFF Delay Time	$t_{D(\text{OFF})}$		16			ns
Fall-Time	$t_F$		23.5			ns
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Maximum Body-Diode Continuous Current	$I_S$				2	A
Maximum Body-Diode Pulsed Current (Note 1)	$I_{SM}$				4	A
Drain-Source Diode Forward Voltage (Note 1)	$V_{SD}$	$I_S=2\text{A}, V_{GS}=0\text{V}$			1.4	V
Body Diode Reverse Recovery Time	$t_{rr}$	$I_S=2\text{A}, V_{GS}=0\text{V},$ $dI_F/dt=100\text{A}/\mu\text{s}$	285			ns
Body Diode Reverse Recovery Charge	$Q_{rr}$		1			$\mu\text{C}$

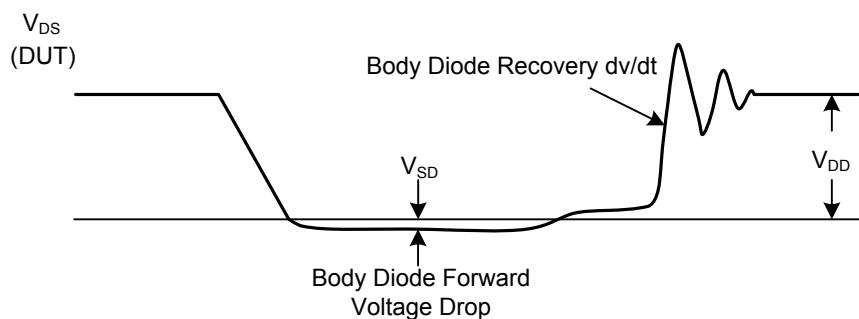
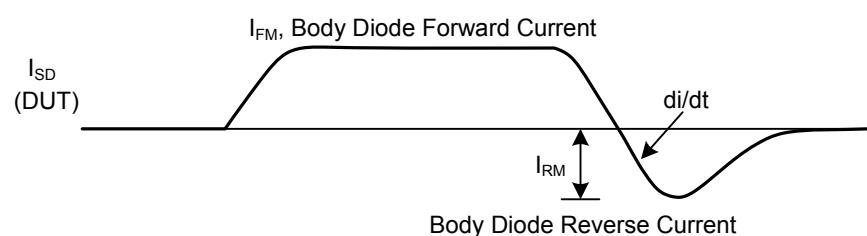
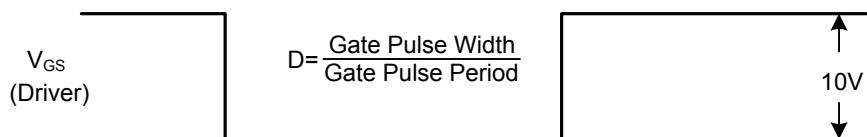
Notes: 1. Pulse Test: Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$ .

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

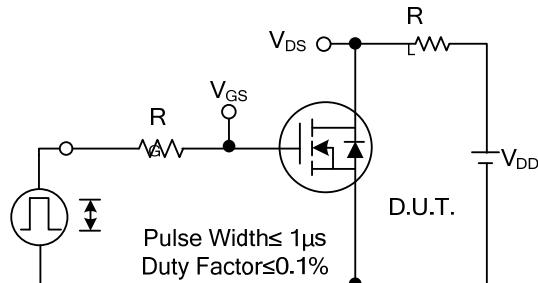


Peak Diode Recovery  $dv/dt$  Test Circuit

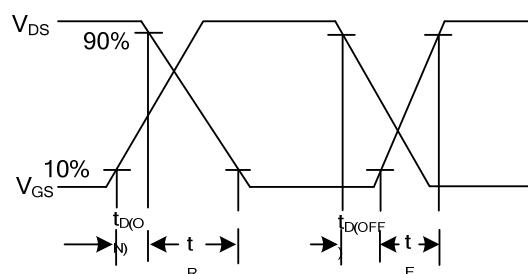


Peak Diode Recovery  $dv/dt$  Waveforms

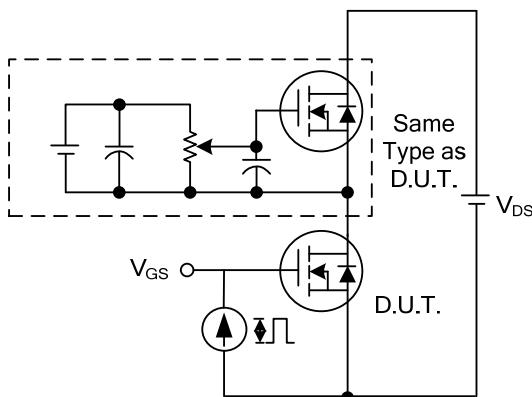
### ■ TEST CIRCUITS AND WAVEFORMS



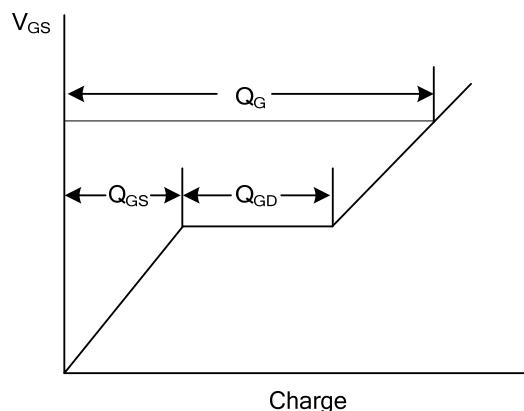
Switching Test Circuit



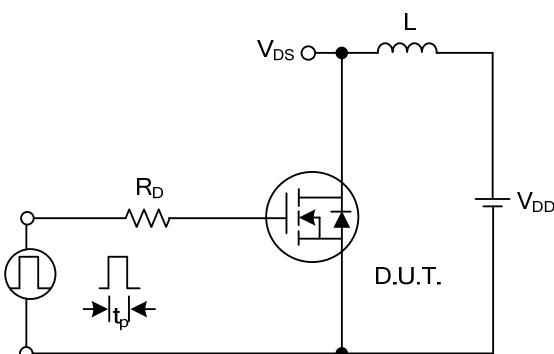
Switching Waveforms



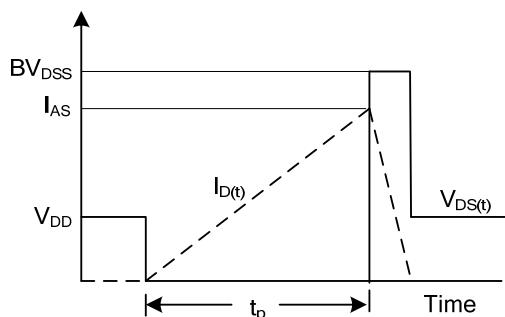
Gate Charge Test Circuit



Gate Charge Waveform

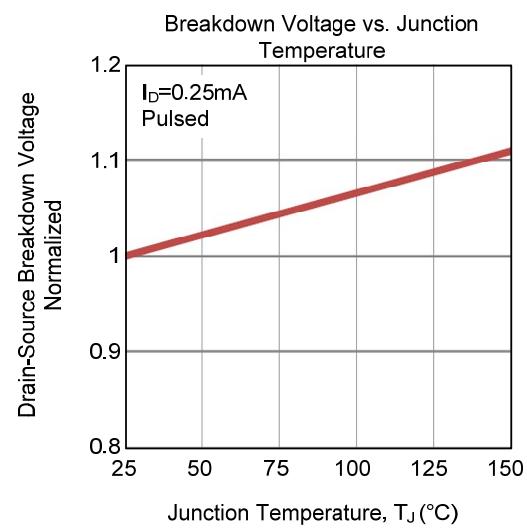
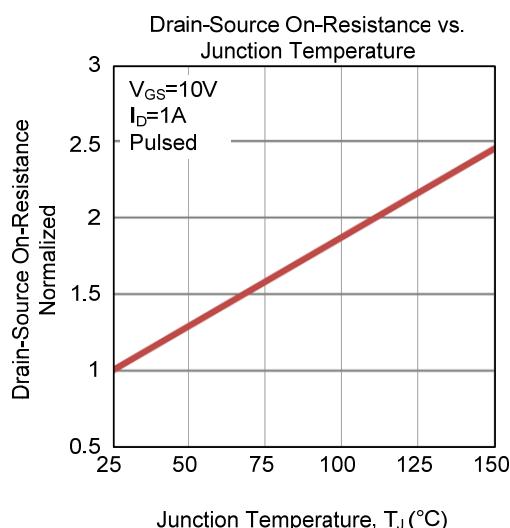
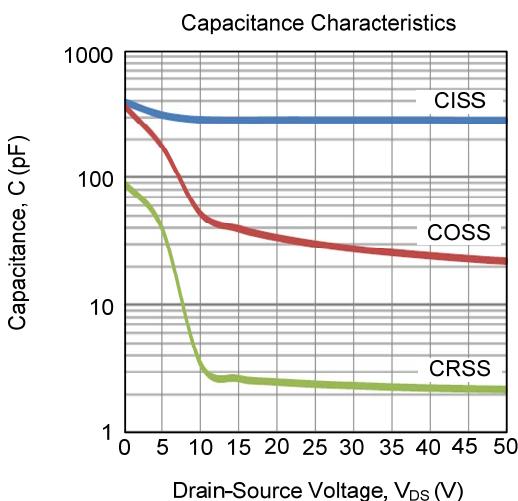
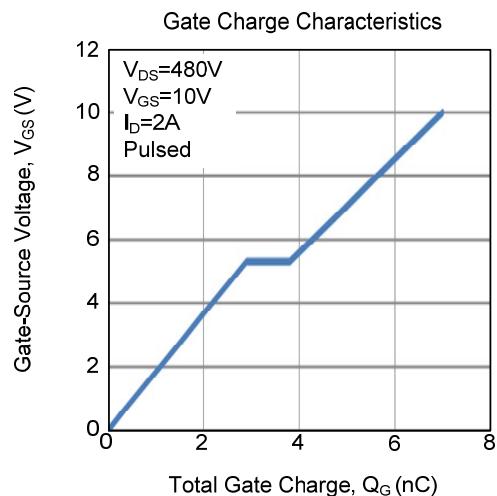
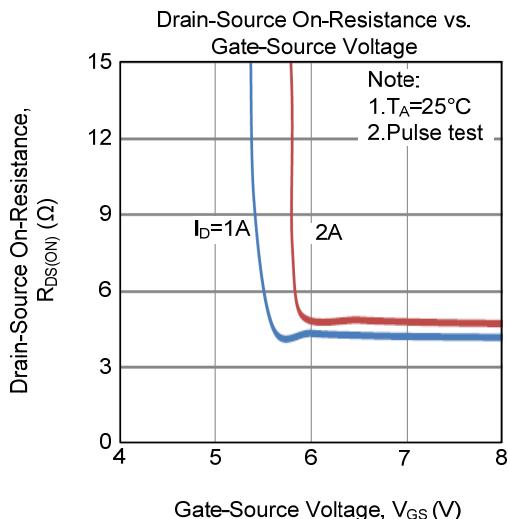
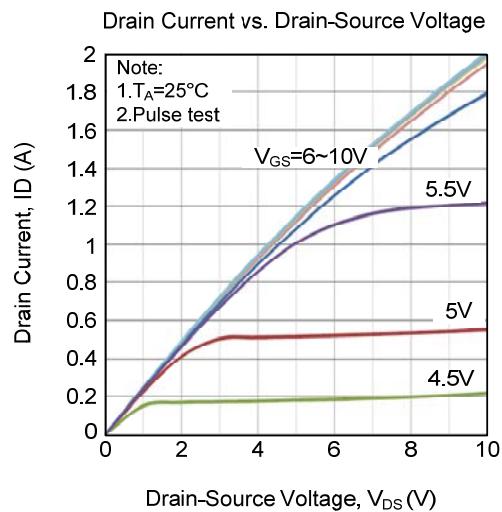


Unclamped Inductive Switching Test Circuit

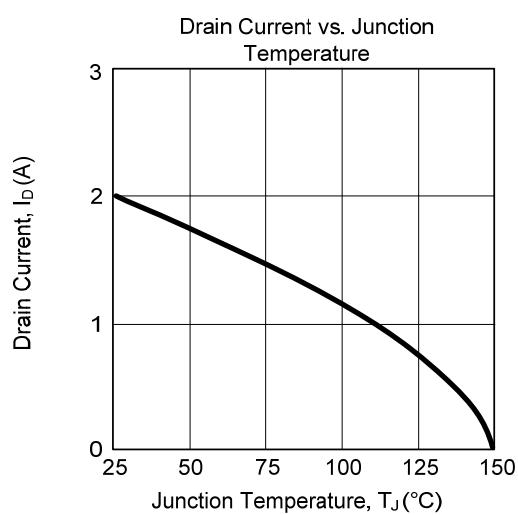
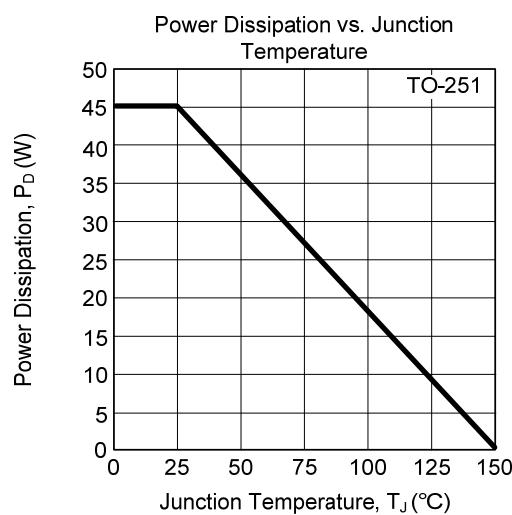
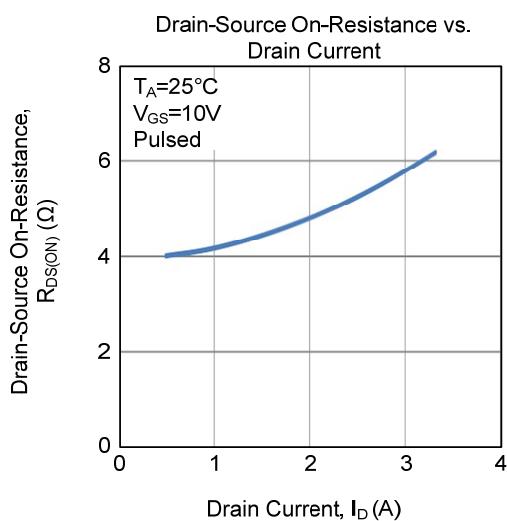
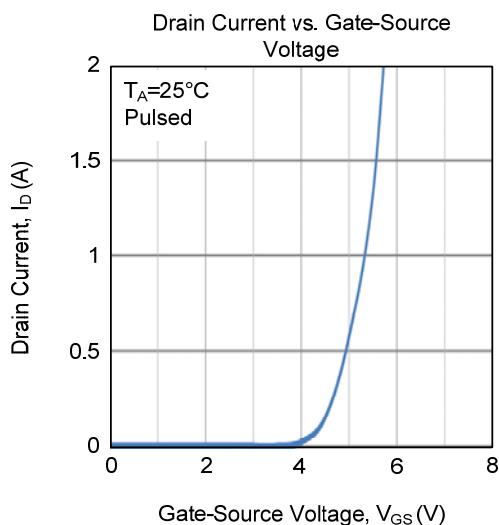
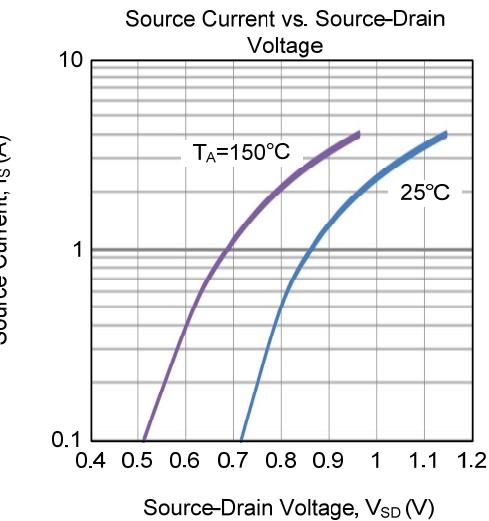
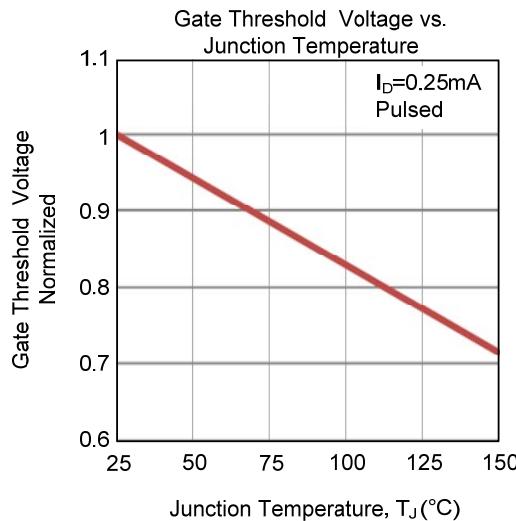


Unclamped Inductive Switching Waveforms

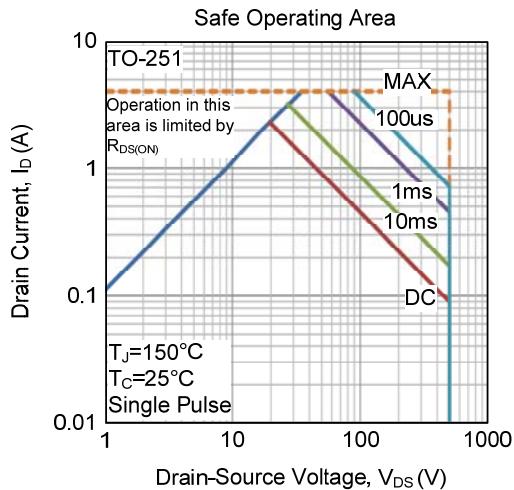
■ TYPICAL CHARACTERISTICS



## ■ TYPICAL CHARACTERISTICS (Cont.)



## ■ TYPICAL CHARACTERISTICS (Cont.)



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